TECHNICAL DATA DATA SHEET 4027, Rev. B

## SILICON SCHOTTKY RECTIFIER DIE Very Low Forward Voltage Drop

## **Applications:**

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

## Features:

- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Reverse Leakage Current
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics
- Electrically / Mechanically Stable during and after Packaging

**Maximum Ratings:** 

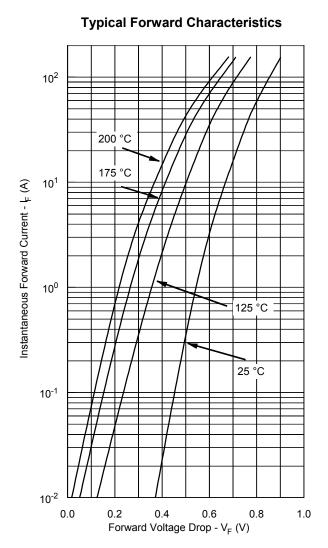
Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	200	V
Max. Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle, rectangular wave form	120	Α
Max. Peak One Cycle Non- Repetitive Surge Current	I <sub>FSM</sub>	10 ms, half Sine pulse	1440	Α
Non-Repetitive Avalanche Energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.3 A, L = 40mH	27	mJ
Repetitive Avalanche Current	I <sub>AR</sub>	$I_{AS}$ decay linearly to 0 in 1 μs f limited by $T_J$ max $V_A$ =1.5 $V_R$	1.3	Α
Max. Junction Temperature	TJ	-	-65 to +200	°C
Max. Storage Temperature	T <sub>stg</sub>	-	-65 to +200	°C

### **Electrical Characteristics:**

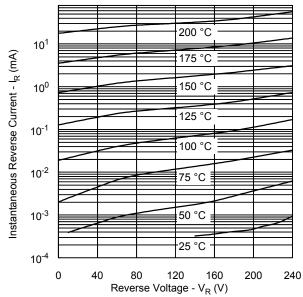
Characteristics	Symbol	bol Condition Max		Units
Max. Forward Voltage Drop	$V_{F1}$	@ 120A, Pulse, T <sub>J</sub> = 25 °C	0.95	V
	$V_{F2}$	@ 120A, Pulse, T <sub>J</sub> = 125 °C	0.79	V
Max. Reverse Current	I <sub>R1</sub>	@V <sub>R</sub> = 200V, Pulse,	2.1	mA
		T <sub>J</sub> = 25 °C		
	$I_{R2}$	@V <sub>R</sub> = 200V, Pulse,	48	mA
		T <sub>J</sub> = 125 °C		
Max. Junction Capacitance	Ст	$@V_R = 5V, T_C = 25  ^{\circ}C$	1800	pF
		$f_{SIG} = 1MHz,$		
		$V_{SIG} = 50 \text{mV (p-p)}$		

<sup>•</sup> World Wide Web Site - http://www.sensitron.com • E-Mail Address - sales@sensitron.com •

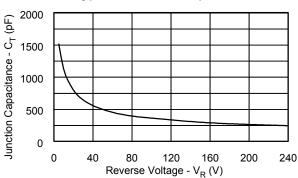
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# Typical Reverse Characteristics



## **Typical Junction Capacitance**



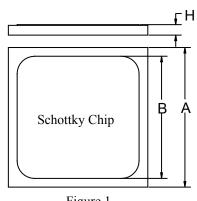
<sup>• 221</sup> West Industry Court ☐ Deer Park, NY 11729-4681 ☐ (631) 586-7600 FAX (631) 242-9798 •

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#### Mechanical Dimensions: In Inches / mm



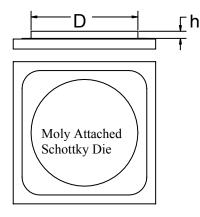


Figure 1

Figure 2

Top side(Anode) metallization: A = Al - 25 kÅ minimum, Figure 1 B = Ag - 30 kÅ minimum, Figure 1 C = Au - 12 kÅ min, Figure 2

Bottom side (Cathode) metallization: A, B, C = Ti/Ni/Ag - 30 kÅ minimum.

A	В	D	Н	h
$0.275\pm0.003$	$0.267 \pm 0.003$	$0.220\pm0.005$	0.0155±0.001	0.011±0.002

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